

SEMICONDUCTOR TECHNICAL DATA

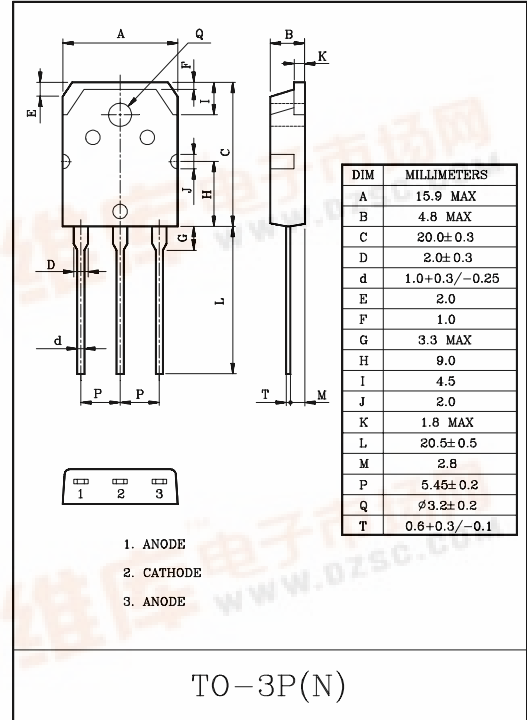
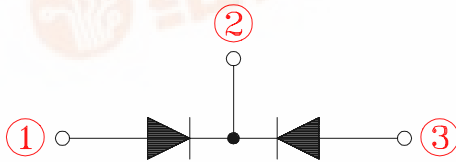
B30A45VN SCHOTTKY BARRIER TYPE DIODE STACK

SWITCHING TYPE POWER SUPPLY APPLICATION,
CONVERTER & CHOPPER APPLICATION.

FEATURES

- Average Output Rectified Current : $I_O=30A$ ($T_c=125^\circ C$).
- Repetitive Peak Reverse Voltage : $V_{RRM}=45V$.
- Fast Reverse Recovery Time : $t_{rr}=35nS$.
- Low Peak Forward Voltage : $0.55V$.(Typ.)

POLARITY



MAXIMUM RATINGS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Repetitive Peak Reverse Voltage	V_{RRM}	45	V
Average Output Rectified Current ($T_c=125^\circ C$) (Rated V_R) (Note)	I_O	30	A
Peak One Cycle Surge Forward Current (Non-Repetitive 60Hz)	I_{FSM}	350	A
Junction Temperature	T_j	-40~150	$^\circ C$
Storage Temperature Range	T_{stg}	-55~150	$^\circ C$

Note : average forward current of centertap full wave connection.

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage (Note)	V_{FM}	$I_{FM}=15A$	-	0.55	0.60	V
Repetitive Peak Reverse Current (Note)	I_{RRM}	$V_{RRM}=\text{Rated}$	-	-	3.0	mA
Reverse Recovery Time (Note)	t_{rr}	$I_F=1.0A, di/dt=-50A/\mu S$	-	-	35	nS
Thermal Resistance (Note)	$R_{th(j-c)}$	Junction to Case	-	-	1.4	$^\circ C/W$

Note : A value of one cell

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